



	ZVP2110GTA	
	Hersteller-Teilenummer:	ZVP2110GTA
	Hersteller / Marke:	Diodes Incorporated
	Teil der Beschreibung:	MOSFET P-CH 100V 0.31A SOT223
	Datenblätter:	 ZVP2110GTA.pdf
	RoHs Status:	Bleifrei / RoHS-konform
<p>Image may be representation. See specs for product details.</p>	Lagerzustand:	New original, 13649 pcs Stock Available.
	Liefern von:	Hong Kong
	Versandweg:	DHL/Fedex/TNT/UPS/EMS

Spezifikationen

Teilenummer	ZVP2110GTA
Hersteller	Diodes Incorporated
Beschreibung	MOSFET P-CH 100V 0.31A SOT223
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	13649 pcs Stock
Serie	-
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-261-4, TO-261AA
Supplier Device-Gehäuse	SOT-223
Verlustleistung (max)	2W (Ta)
Typ FET	P-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	100V
Strom - Ununterbrochener Abfluss (Id) bei 25 °C	310mA (Ta)
Rds On (Max) @ Id, Vgs	8 Ohm @ 375mA, 10V
VGS (th) (Max) @ Id	3.5V @ 1mA
Gate Charge (Qg) (Max) @ Vgs	-
Eingabekapazität (Ciss) (Max) @ Vds	100pF @ 25V
Antriebsspannung (Max Rds On, Min Rds On)	10V
Vgs (Max)	±20V
Verpackung	Original-Reel®

























ZVP2110GTA ist neu im Original, Suche ZVP2110GTA Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie ZVP2110GTA Diodes Incorporated mit Garantie und Vertrauen.
Anfrage ZVP2110GTA: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>ZVP2110ASTOA Diodes Incorporated MOSFET P-CH 100V 0.23A TO92-3</p>	 <p>ZVP2120A Diodes Incorporated MOSFET P-CH 200V 0.12A TO92-3</p>	 <p>ZVP2110AST ZEXTX ZEXTX TO-92S</p>	 <p>ZVP2110ASTOB Diodes Incorporated MOSFET P-CH 100V 0.23A TO92-3</p>
 <p>ZVP2120ASTOB Diodes Incorporated MOSFET P-CH 200V 0.12A TO92-3</p>	 <p>ZVP2120ASTOA Diodes Incorporated MOSFET P-CH 200V 0.12A TO92-3</p>	 <p>ZVP2110G ZETEX ZVP2110G ZETEX</p>	 <p>ZVP2110ASTZ Diodes Incorporated MOSFET P-CH 100V 0.23A TO92-3</p>

heiße Teile

Mehr

 ACAS2R5S101E18	 C1005X7R1V153K050BB	 CP0069AH	 D CSTCW48M0X12058-R0	 GCM0335C1E7R3DD03D
 GRM1555C2A9R9CA01J	 GRM1885C1H362JA01D	 D LT3466EDD-1#TRPBF	 MAX16823AUE/V+	 N510CH16
 NPH10S2412EI	 NTE4151P1G	 ONET4291PARGVRG4	 PBH-24-009	 PE-62892
 D ZVP0535A	 ZVP0545A	 ZVP0545ASTZ	 ZVP0545GTA	 ZVP1320FTA
 ZVP2106ASTOA	 ZVP2106ASTZ	 ZVP2106G	 ZVP2106GTA	 ZVP2106GTC
 ZVP2110A	 ZVP2110ASTZ	 D ZVP2110G	 ZVP2110GTC	 ZVP2120ASTZ
 ZVP2120GTA	 D ZVP3306A	 ZVP3306F	 ZVP3306FTA	 ZVP3306FTC
 ZVP3310FTA	 ZVP4105A	 ZVP4105ASTOA	 ZVP4105ASTZ	 ZVP4424A
 ZVP4424ASTZ	 ZVP4424GTA	 ZVP4424GTC	 D ZVP4424ZQTA	 ZVP4424ZTA
 ZVP4525E6TA	 ZVP4525GTA	 ZVP4525TA	 ZVP4525ZTA	 ZVP81982F0

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